

SGM4915 Dual 145mW Headphone Amplifier with Active Low Shutdown Mode

GENERAL DESCRIPTION

The SGM4915 is a dual audio power amplifier with active low shutdown mode. It is designed to maximize audio performance in portable applications. The audio power amplifier is designed for the portable application that needs low-component count and can operate from a single 2.5V to 5.5V power supply. Under the condition of using a 5.0V power supply to drive a 16Ω speaker, it can deliver a continuous average power of 145mW per channel, and the distortion (THD) is less than 0.1%.

The SGM4915 provides an active-low, micro-power consumption shutdown mode which is controlled externally and an internal thermal shutdown protection.

The SGM4915 is applied to low power portable systems. Bootstrap capacitors or snubber networks are not needed.

The SGM4915 provides an externally controlled gain (with resistors), as well as an externally controlled turn-on time (with the bypass capacitor) for maximum flexibility.

The SGM4915 is available in a Green TDFN-2×2-8L package. It operates over an ambient temperature range of -40°C to +85°C.

FEATURES

- Supply Voltage Range: 2.5V to 5.5V
- Active Low Shutdown Mode
- 145mW into 16Ω Load from 5V Power Supply at THD+N = 0.1% (Typical, per Channel)
- 82mW into 32Ω Load from 5V Power Supply at THD+N = 0.1% (Typical, per Channel)
- Unity Gain Stable
- Shutdown Current: 0.02μA (TYP)
- Shutdown Pin is Compatible with 1.8V Logic
- Pop/Click Reduction Circuitry
- -40°C to +85°C Operating Temperature Range
- Available in a Green TDFN-2×2-8L Package

APPLICATIONS

Mobile Phone
Portable Systems
Headphone Amplifier
Notebook Computers
Microphone Preamplifier
PDAs
GPS



PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION	
SGM4915	TDFN-2×2-8L	-40°C to +85°C	SGM4915YDE8G/TR	4915 XXXX	Tape and Reel, 3000	

MARKING INFORMATION

NOTE: XXXX = Date Code.

XXXX

Date Code - Week

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS

- Date Code - Year

Supply Voltage	6V
Input Voltage	$0.3V \text{ to } (V_{CC}) + 0.3V$
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	2000V
MM	200V

RECOMMENDED OPERATING CONDITIONS

Supply Voltage Range	2.5V to 5.5V
Operating Temperature Range	40°C to +85°C

OVERSTRESS CAUTION

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

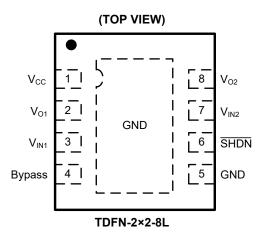
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION



PIN DESCRIPTIONS

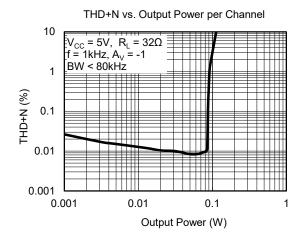
PIN	NAME	DESCRIPTION
1	C1P	Positive Terminal for Flying Capacitor. Connect a 1µFcapacitor to C1N.
2	PGND	Power Ground. Connect to SGND.
3	C1N	Negative Terminal for Flying Capacitor. Connect a 1µF capacitor to C1P.
4	PVss	Charge-Pump Output. Connect to SV _{SS} and bypass with a 1µF ceramic capacitor to PGND.
5	SHDN	Active-Low Shutdown Input.
6	INL	Input for Left-Channel.
7	SGND	Signal Ground. Connect to PGND.
8	INR	Input for Right-Channel.
9	SV _{SS}	Amplifier Negative Supply. Connect to PV _{SS} .
10	OUTR	Output for Right-Channel.
11	OUTL	Output for Left-Channel.
12	V_{DD}	Positive Power-Supply Input. Bypass with a 1µF capacitor to SGND.
Exposed Pad	_	Exposed Pad. Can be connected to GND or left floating.

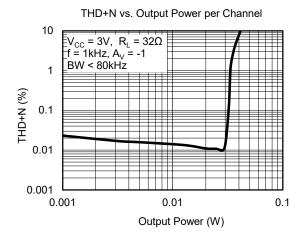
ELECTRICAL CHARACTERISTICS

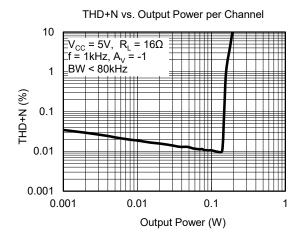
(T_A = +25°C, unless otherwise noted.)

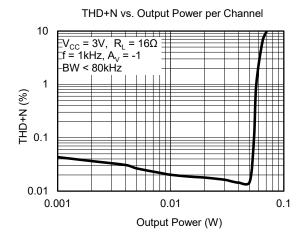
PARAMETER	SYMBOL		CONDITIONS		MIN	TYP	MAX	UNITS
					2.5		5.5	V
$V_{IN} = 0V$, $V_{SHDN} = GND$, $V_{CC} = 5.0V$				0.02	4			
Shutdown Current	I _{SD}	$V_{IN} = 0V$, $V_{SHDN} = GND$, $V_{CC} = 3.3V$				0.02		μΑ
		$V_{IN} = 0V$, $V_{SHDN} = GND$, $V_{CC} = 2.6V$				0.02		
		$V_{IN} = 0V$, $V_{SHDN} = V$	_{CC} = 5.0V		-50	2.5	50	mV
Output Offset Voltage	Vos	$V_{IN} = 0V$, $V_{SHDN} = V$	_{CC} = 3.3V			2.5		
		$V_{IN} = 0V, V_{SHDN} = V$	_{CC} = 2.6V			2.5		
			V_{CC} = 5.0V, No	o Load		1.65	2.8	
Quiescent Power Supply Current	ΙQ	$V_{IN} = 0V,$ $V_{SHDN} = V_{CC}$	$V_{CC} = 3.3V, No.$	o Load		1.50		mA
			V _{CC} = 2.6V, No	o Load		1.40		
Shutdown Voltage Input High	V_{SDIH}				1.2			V
Shutdown Voltage Input Low	V_{SDIL}						0.4	V
	Po	f = 1kHz THD+N = 0.1%	V _{CC} = 5.0V	$R_L = 16\Omega$		145		mW
				$R_L = 32\Omega$		85		
			V _{CC} = 3.6V	$R_L = 16\Omega$		78		
Output Power (per Channel)				$R_L = 32\Omega$		44		
Catput Forms (per Griannel)			V _{CC} = 3.0V	$R_L = 16\Omega$		54		
				$R_L = 32\Omega$		31		
			V _{CC} = 2.6V	$R_L = 16\Omega$		40		
				$R_L = 32\Omega$		23		
Total Harmonic Distortion + Noise	THD+N	$P_0 = 78$ mW, $V_{CC} = $ f = 20Hz to 20kHz		,		0.1		%
Crosstalk	X _{talk}	$R_L = 32\Omega, P_O = 70$	mW, V _{CC} = 5V, f	= 1kHz		-85		dB
				V _{CC} = 5.0V		-67		
		f = 217Hz, C _B = 1 _k	$_{\rm IF}$, $R_{\rm L}$ = 32Ω	V _{CC} = 3.6V		-67		- dD
		V _{RIPPLE} = 200mVp- Input Grounded w	·ρ, ith 10Ω	V _{CC} = 3.0V		-65		
Dower Cumply Deignting Datin	PSRR			V _{CC} = 2.6V		-64		
Power Supply Rejection Ratio		f = 1kHz, C_B = 1μF, R_L = 32 Ω V_{RIPPLE} = 200mVp-p, Input Grounded with 10 Ω		V _{CC} = 5.0V		-75		- dB - -
				V _{CC} = 3.6V		-75		
				V _{CC} = 3.0V		-74		
				V _{CC} = 2.6V		-65		

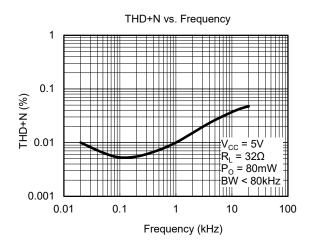
TYPICAL PERFORMANCE CHARACTERISTICS

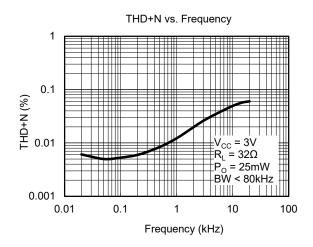




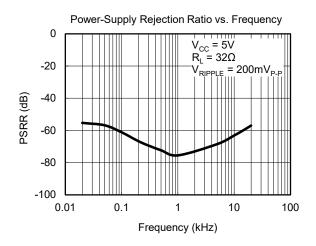


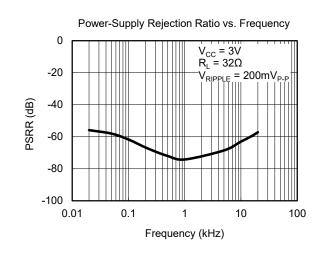


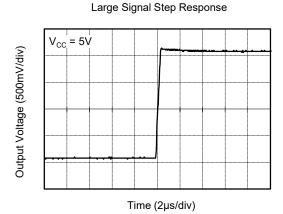


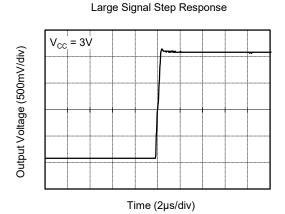


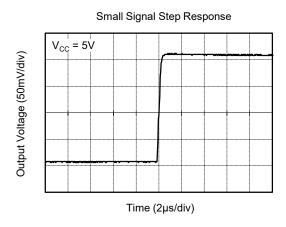
TYPICAL PERFORMANCE CHARACTERISTICS (continued)

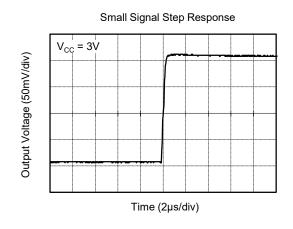




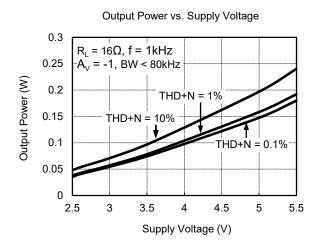


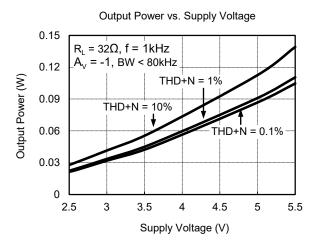


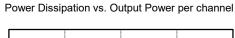


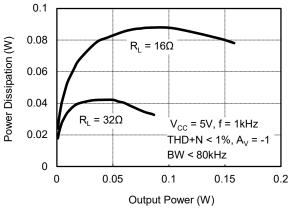


TYPICAL PERFORMANCE CHARACTERISTICS (continued)









Dual 145mW Headphone Amplifier with Active Low Shutdown Mode

SGM4915

REVISION HISTORY

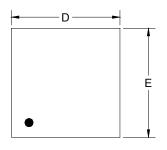
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

MAY 2011 - REV.A to REV.A.1

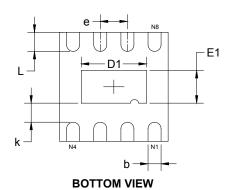
Changes from Original (MARCH 2010) to REV.A

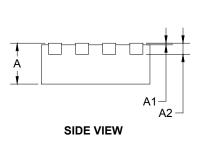


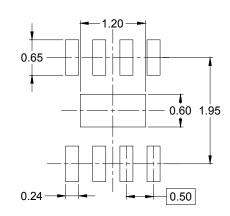
PACKAGE OUTLINE DIMENSIONS TDFN-2×2-8L



TOP VIEW





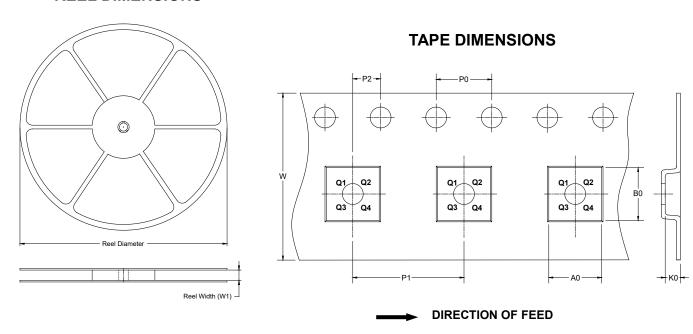


RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	_	nsions meters	Dimensions In Inches		
,	MIN	MAX	MIN	MAX	
Α	0.700	0.800	0.028	0.031	
A1	A1 0.000 0.050		0.000	0.002	
A2	0.203	REF	0.008	REF	
D	1.900	2.100	0.075	0.083	
D1	1.100	1.300	0.043	0.051	
E	1.900	2.100	0.075	0.083	
E1	0.500	0.700	0.020	0.028	
k	0.200 MIN		0.008	3 MIN	
b	0.180	0.300	0.007	0.012	
е	0.500 TYP		0.020	TYP	
L	0.250	0.450	0.010	0.018	

TAPE AND REEL INFORMATION

REEL DIMENSIONS

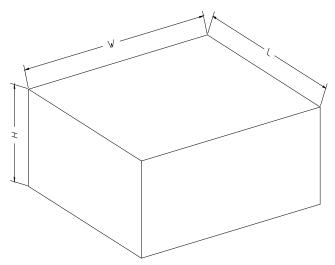


NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TDFN-2×2-8L	7"	9.5	2.30	2.30	1.10	4.0	4.0	2.0	8.0	Q1

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18